



30V DUAL P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BVDSS	RDS(ON) Max	I _D T _A = +25°C	
-30V	$28m\Omega @V_{GS} = -10V$	-6.0A	
-307	$45m\Omega @V_{GS} = -4.5V$	-4.7A	

Description

This new generation MOSFET has been designed to minimize the onstate resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

Applications

- DC-DC converters
- Power-management functions
- Load switches

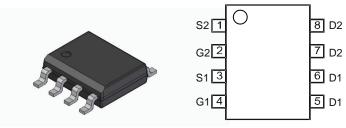
Features

- Low Input Capacitance
- Low On-Resistance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMP3028LSDQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

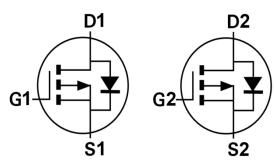
Mechanical Data

- Package: SO-8
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Tin Finish Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (a)
- Weight: 0.074 grams (Approximate)



Top View

Pin Configuration



Equivalent Circuit

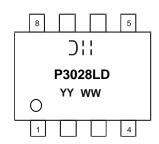
Ordering Information (Note 4)

Part Number	Packago	Packing		
Part Number	Fackage	Qty.	Carrier	
DMP3028LSDQ-13	SO-8	2,500	Tape & Reel	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



⊃¦¦ = Manufacturer's Marking P3028LD = Product Type Marking Code YYWW = Date Code Marking YY or YY = Year (ex: 24 = 2024) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	-30	V		
Gate-Source Voltage	V _{GSS}	±20	V		
Continuous Drain Current (Note E) V 40V	Steady State	T _A = +25°C T _A = +70°C	l _D	-6 -4.7	А
Continuous Drain Current (Note 5) V _{GS} = 10V	t<10s	T _A = +25°C T _A = +70°C	lo	-7.4 -5.8	А
Maximum Body Diode Forward Current (Note 6)	Is	-2.5	Α		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	I _{DM}	-30	Α		

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	D-	1.3	W
Total Power Dissipation (Note 5)	$T_A = +70^{\circ}C$	PD	0.8	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	102	°C/W
mermal Resistance, Junction to Ambient (Note 5)	t<10s	Көја	61	
Total Power Dissipation (Note 6)	$T_A = +25$ °C	Po	1.7	W
Total Power Dissipation (Note 6)	$T_A = +70^{\circ}C$	PD	1.1	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	75	
Thermal Resistance, Junction to Ambient (Note o)	t<10s	Reja	50	°C/W
Thermal Resistance, Junction to Case (Note 6)	Rejc	14.5		
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

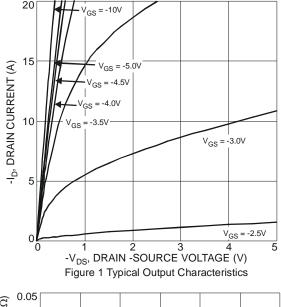
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	-30	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	-1	μΑ	V _{DS} = -30V, V _{GS} = 0V	
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(th)}	-1	_	-3	V	$V_{DS} = V_{GS}$, $I_D = -250\mu A$	
Static Drain-Source On-Resistance		1	20	28	mΩ	$V_{GS} = -10V, I_{D} = -7A$	
Static Drain-Source On-Resistance	RDS(ON)	_	29	45		V _G S = -4.5V, I _D = -5.5A	
Forward Transfer Admittance	Y _{fs}	_	11	_	S	$V_{DS} = -5V, I_{D} = -7A$	
Diode Forward Voltage	VsD	_	0.7	1.2	V	Vgs = 0V, Is = -2.1A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		1241	_		V _{DS} = -15V, V _{GS} = 0V f = 1.0MHz	
Output Capacitance	Coss		147	_	pF		
Reverse Transfer Capacitance	Crss	_	110	_			
Gate Resistance	Rg	_	15	_	Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1.0MHz	
Total Gate Charge (Vgs = -4.5V)	Qg	_	11	_			
Total Gate Charge (V _{GS} = -10V)	Qg	_	22	_	nC	$V_{DS} = -15V, I_{D} = -7A$	
Gate-Source Charge	Qgs	_	3.5	_	nc nc		
Gate-Drain Charge	Q_{gd}	_	4.7	_			
Turn-On Delay Time	t _{D(on)}	_	9.7	_			
Turn-On Rise Time	tr	_	17.1	_		$V_{GS} = -10V$, $V_{DD} = -15V$, $R_{GEN} = 6\Omega$,	
Turn-Off Delay Time	t _{D(off)}	_	60.5	_	ns	$I_D = -7A$	
Turn-Off Fall Time	tf		40.4	_			

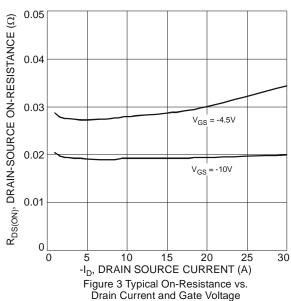
Notes:

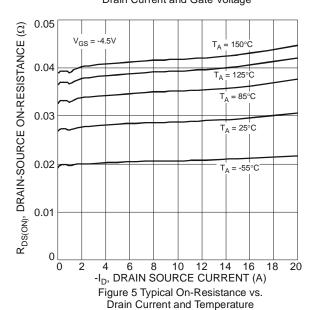
- 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to product testing.

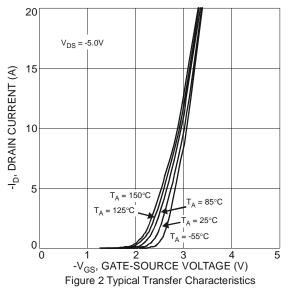


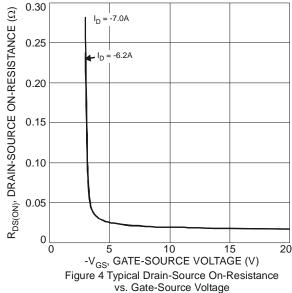












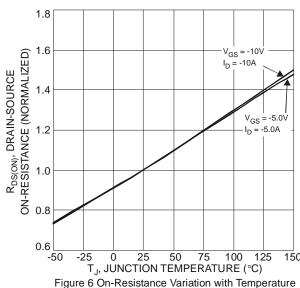
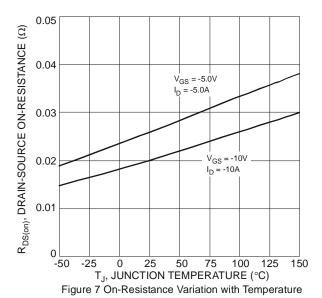
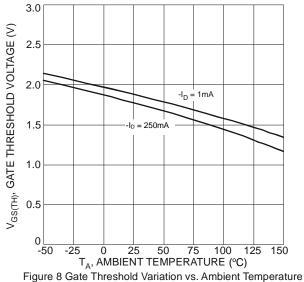


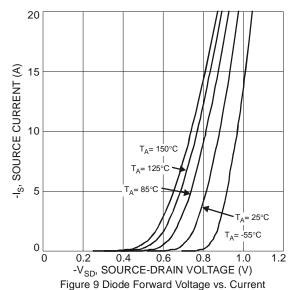
Figure 6 On-Resistance Variation with Temperature







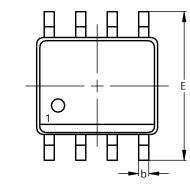


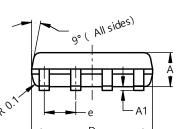


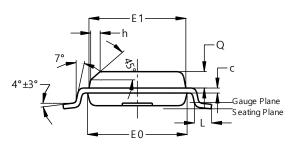


Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.







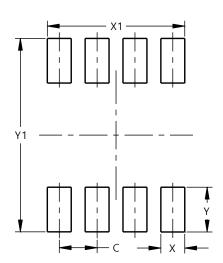
SO-8

SO-8						
Dim	Min	Max	Тур			
Α	1.40	1.50	1.45			
A1	0.10	0.20	0.15			
b	0.30	0.50	0.40			
С	0.15	0.25	0.20			
D	4.85	4.95	4.90			
Е	5.90	6.10	6.00			
E1	3.80	3.90	3.85			
E0	3.85	3.95	3.90			
е			1.27			
h			0.35			
L	0.62	0.82	0.72			
Q	0.60	0.70	0.65			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8



Dimensions	Value (in mm)				
С	1.27				
Х	0.802				
X1	4.612				
Y	1.505				
V1	6.50				



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